



# 50A02MH

## Low-Frequency General-Purpose Amplifier Applications

An ON Semiconductor Company

### Applications

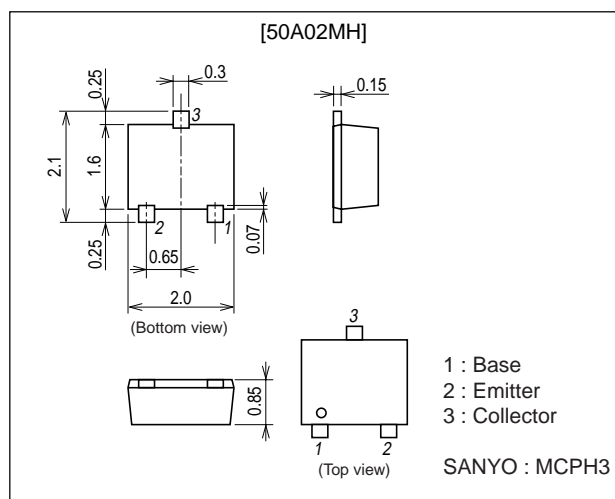
- Low-frequency Amplifier, high-speed switching, small motor drive, muting circuit.

### Features

- Large current capacitance.
- Low collector-to-emitter saturation voltage (resistance).  
RCE(sat) typ=210mΩ [IC=0.5A, IB=50mA].
- Small ON-resistance (Ron).

### Package Dimensions

unit : mm  
2194A



### Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		-50	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		-50	V
Emitter-to-Base Voltage	V <sub>EB0</sub>		-5	V
Collector Current	I <sub>C</sub>		-500	mA
Collector Current (Pulse)	I <sub>CP</sub>		-1.0	A
Collector Dissipation	P <sub>C</sub>	Mounted on a ceramic board (600mm <sup>2</sup> X0.8mm)	600	mW
Junction Temperature	T <sub>J</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CB0</sub>	V <sub>CB</sub> =-40V, I <sub>E</sub> =0			-100	nA
Emitter Cutoff Current	I <sub>EB0</sub>	V <sub>EB</sub> =-4V, I <sub>C</sub> =0			-100	nA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =-2V, I <sub>C</sub> =-10mA	200		500	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-50mA		690		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, f=1MHz		3.8		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-100mA, I <sub>B</sub> =-10mA		-60	-120	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =-100mA, I <sub>B</sub> =-10mA		-0.9	-1.2	V

Marking : AM

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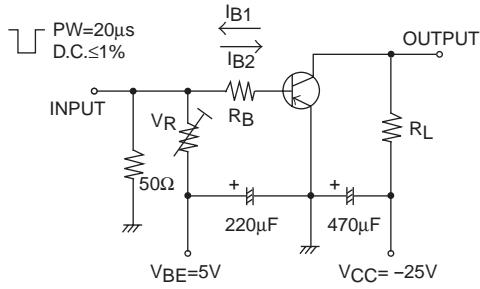
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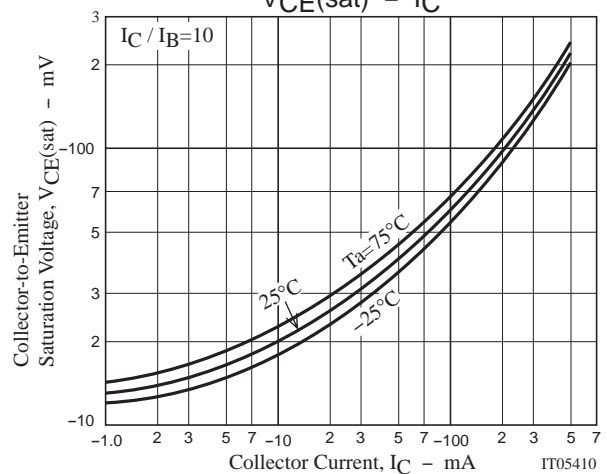
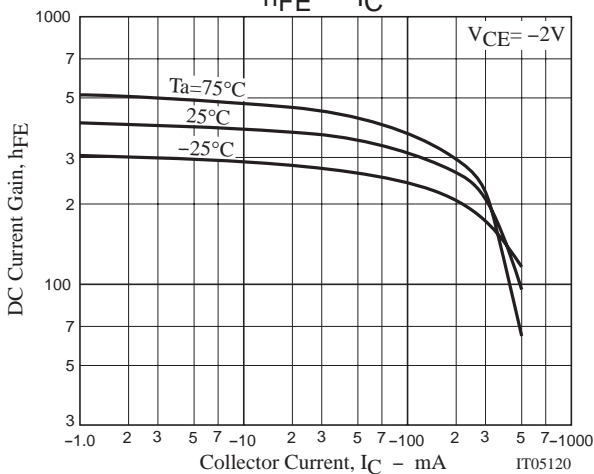
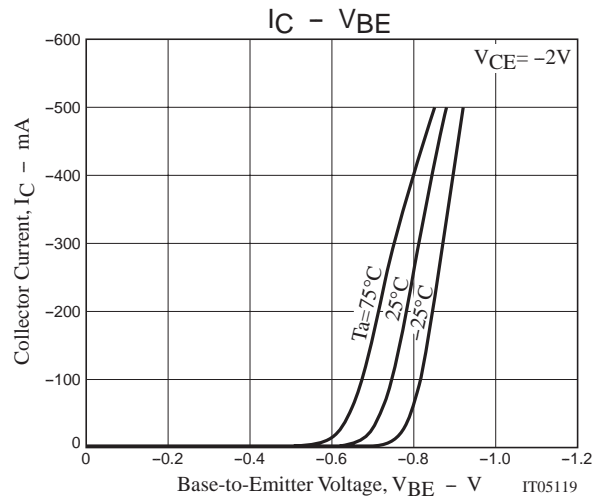
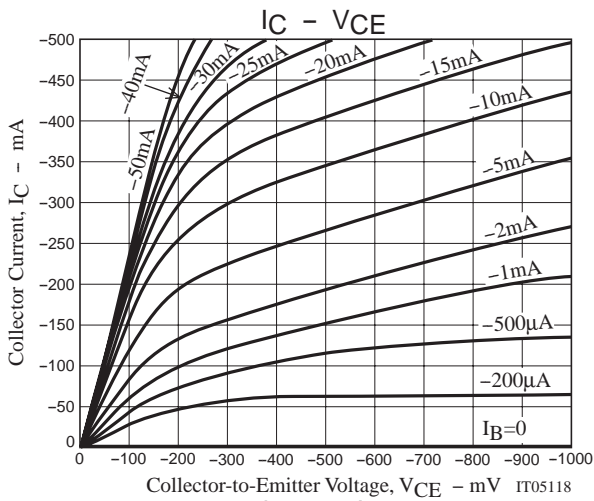
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu A, I_E = 0$	-50			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1mA, R_{BE} = \infty$	-50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu A, I_C = 0$	-5			V
Turn-ON Time	$t_{on}$	See specified Test Circuit.		30		ns
Storage Time	$t_{stg}$	See specified Test Circuit.		170		ns
Fall Time	$t_f$	See specified Test Circuit.		30		ns

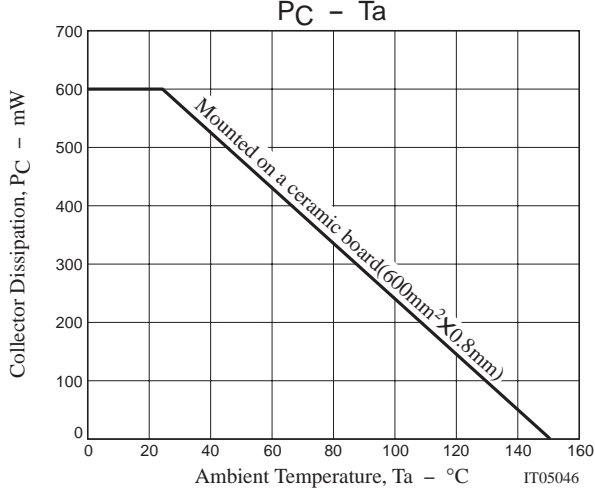
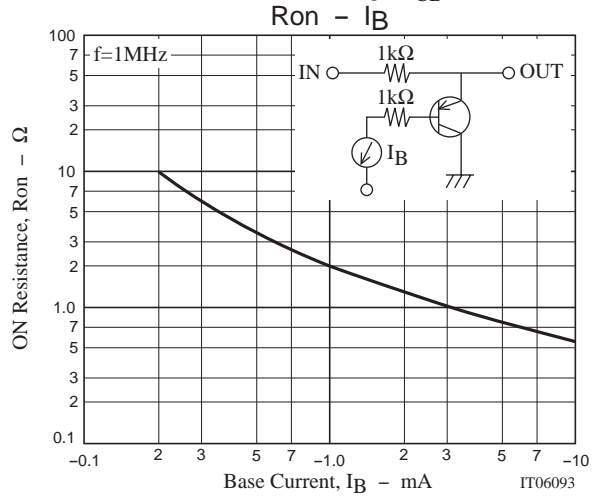
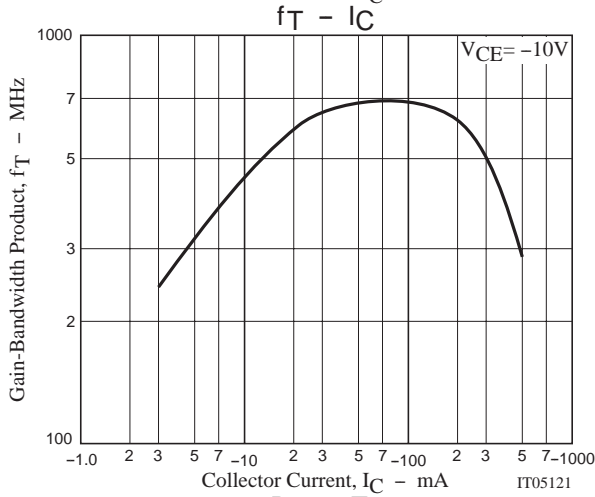
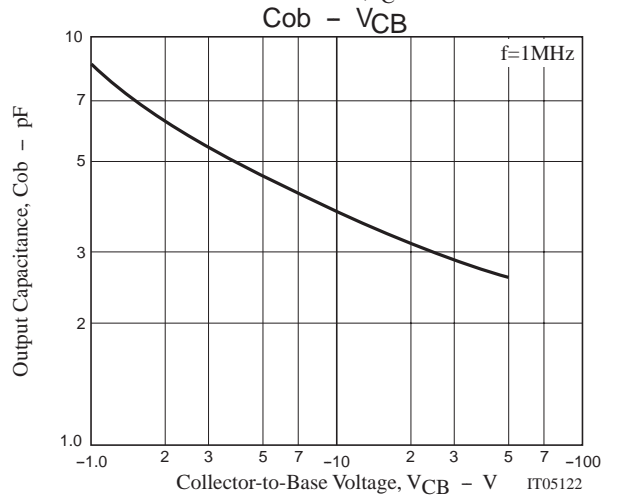
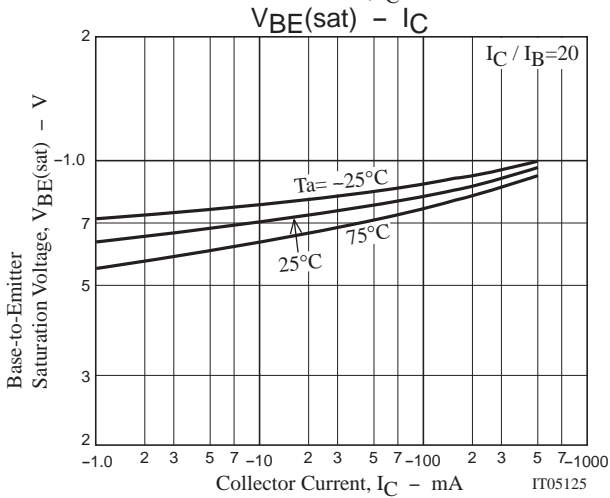
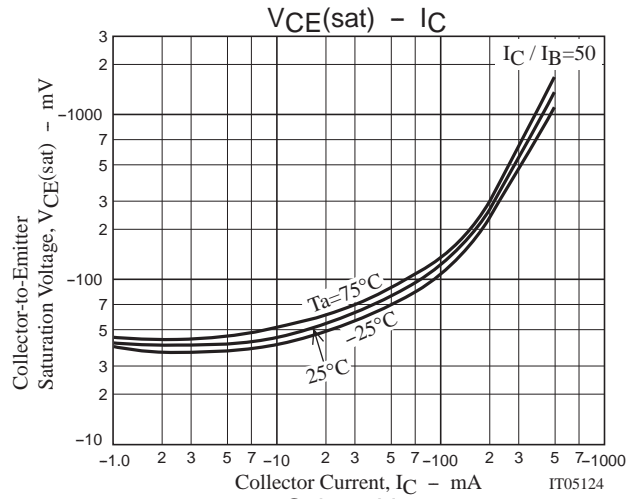
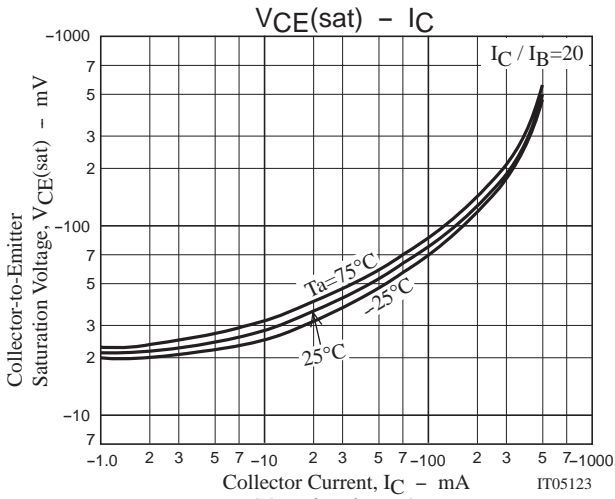
## Switching Time Test Circuit



$$I_C = 20I_{B1} = -20I_{B2} = -200mA$$



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